

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	955	(semiconductor with channel\$5) same stripe\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 13:35
L2	137	((thin adj film adj transistor) TFT) and 1 and @ad<"20040112"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 13:36
L3	947	((thin adj film) TFT) and semiconductor and (laser with irradiat\$5)) and (349/42,43.ccls. 257/59,66,72,74.ccls. 345/92.ccls.) and @ad<"20040112"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 14:06
L4	68866	3 and (channel same defect) (crystal\$5 same defect) (semiconductor same (stripe heterogeneous))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 14:06
L5	322	3 and ((channel same defect) (crystal\$5 same defect) (semiconductor same (stripe heterogeneous)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 14:06
L6	21	((thin adj film) TFT) and (semiconductor\$5 with channel) and (laser with irradiat\$5) and ((crystal\$5 near2 boundary) (defect stripe (heterogeneous adj2 line))). CLM.	US-PGPUB	OR	ON	2007/01/03 14:10
L7	17	6 and @ad<"20040112"	US-PGPUB	OR	ON	2007/01/03 14:10